INTEGRATED CIRCUITS



Product specification

1998 Jul 27

IC24 Data Handbook



HILIP

74ALVCH16825

FEATURES

- Wide supply voltage range of 1.2V to 3.6V
- Complies with JEDEC standard no. 8-1A.
- CMOS low power consumption
- Direct interface with TTL levels
- Current drive ± 24 mA at 3.0 V
- MULTIBYTETM flow-through standard pin-out architecture
- Low inductance multiple V_{CC} and GND pins for minimum noise and ground bounce
- All data inputs have bus hold
- Output drive capability 50Ω transmission lines @ 85°C

DESCRIPTION

The 74ALVCH16825 is an 18-bit non-inverting buffer/driver with 3-State outputs for bus-oriented applications.

The 74ALVCH16825 consists of two 9-bit sections with separate output enable signals. For either 9-bit buffer section, the two output enable (10E1 and 10E2 or 20E1 and 20E2) inputs must both be LOW for corresponding D outputs to be active. If either output enable input is HIGH, the outputs of that 9-buffer section are in the high impedance state.

The 74ALVCH16825 has active bus hold circuitry which is provided to hold unused or floating data inputs at a valid logic level. This feature eliminates the need for external pull-up or pull-down resistors.

10E2 10E1 56 1 55 1Y₁ 2 $1A_0$ 54 1Y₁ 3 1A₁ GND 4 53 GND 52 1Y₂ 5 $1A_2$ 51 6 $1Y_3$ $1A_3$ V_{CC} 7 50 V_{CC} 49 1Y₄ 8 $1A_4$ 48 1Y₅ 9 1A₅ 47 10 $1Y_6$ $1A_6$ 46 GND 11 GND 1Y₇ 12 45 1A₇ 44 13 1A₈

PIN CONFIGURATION

1Y₈ 43 GND 14 GND 42 GND GND 15 41 2Yo 16 2A0 40 $2Y_1$ 17 $2A_1$ 39 GND GND 18 38 19 2Y₂ $2A_2$ 37 $2Y_3$ 20 $2A_3$ 21 36 2Y₄ $2A_4$ V_{CC} 22 35 V_{CC} 2Y₅ 34 2A5 23 33 2Y₆ 24 2A₆ 32 GND GND 25 31 26 $2Y_7$ 2A7 27 30 $2Y_8$ $2A_8$ 2<u>0E</u>1 28 29 20E2

SH00139

QUICK REFERENCE DATA

GND = 0V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5$ ns

SYMBOL	PARAMETER	CONDITION	TYPICAL	UNIT	
t _{PHL} /t _{PLH}	Propagation delay CP to Qn	$V_{CC} = 2.5V, C_L = 30pF$ $V_{CC} = 3.3V, C_L = 50pF$		2.0 2.0	ns
Cl	Input capacitance			4.0	pF
C _{PD}	Power dissipation capacitance per latch	$V_1 = GND$ to V_{CC}^1	Output enabled	19	pF
CPD	Tower dissipation capacitance per laten		Output disabled	3	рі

NOTES:

 C_{PD} is used to determine the dynamic power dissipation (P_D in μ W): 1.

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where: $f_i = \text{input frequency in MHz}; C_L = \text{output load capacitance in pF};$ $f_o = \text{output frequency in MHz}; V_{CC} = \text{supply voltage in V}; \Sigma (C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs}.$

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DRAWING NUMBER
56-Pin Plastic Thin Shrink Small Outline (TSSOP) Type II	–40°C to +85°C	74ALVCH16825 DGG	ACH16825 DGG	SOT364-1

74ALVCH16825

PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1	1OE1	Output enable input
56	10E2	(active LOW)
55, 54, 52, 51, 49, 48, 47, 45, 44	1A0 to 1A8	Data inputs
2, 3, 5, 6, 8, 9, 10, 12, 13	1Y0 to 1Y8	Data outputs
4, 11, 14, 15, 18, 25, 32, 39, 42, 43, 46, 53	GND	Ground (0V)
7, 22, 35, 50	V _{CC}	Positive supply voltage
28	20E1	Output enable input
29	2 0E 2	(active LOW)
43, 42, 41, 40, 38, 37, 36, 34, 33, 31	2A0 to 2A8	Data inputs
16, 17, 19, 20, 21, 23, 24, 26, 27	2Y0 to 2Y8	Data outputs

LOGIC SYMBOL



FUNCTION TABLE

	INPUTS			
nOE1	nOE2	A	Y	
L	L	L	L	
L	L	Н	Н	
Н	Х	Х	Z	
Х	Н	Х	Z	

HIGH voltage level Н = L X

LOW voltage level =

= Don't care

Ζ High impedance "off" state =

LOGIC SYMBOL (IEEE/IEC)



74ALVCH16825

LOGIC DIAGRAM





RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V	DC supply voltage 2.5V range (for max. speed performance @ 30 pF output load)		2.3	2.7	N
V _{CC}	DC supply voltage 3.3V range (for max. speed performance @ 50 pF output load)		3.0	3.6	· V
VI	DC Input voltage range		0	V _{CC}	V
Vo	DC output voltage range		0	V _{CC}	V
T _{amb}	Operating free-air temperature range		-40	+85	°C
t _r , t _f	Input rise and fall times	$V_{CC} = 2.3 \text{ to } 3.0 \text{V}$ $V_{CC} = 3.0 \text{ to } 3.6 \text{V}$	0 0	20 10	ns/V

ABSOLUTE MAXIMUM RATINGS

In accordance with the Absolute Maximum Rating System (IEC 134) Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V ₁ <0	-50	mA
V _I DC input voltage		For control pins ²	-0.5 to +4.6	v
٧I	DC input voltage	For data inputs ²	–0.5 to V _{CC} +0.5	Ň
I _{OK}	DC output diode current	$V_{O} > V_{CC} \text{ or } V_{O} < 0$	±50	mA
V _O	DC output voltage	Note 2	–0.5 to V _{CC} +0.5	V
Ι _Ο	DC output source or sink current	$V_{O} = 0$ to V_{CC}	±50	mA
I _{GND} , I _{CC}	DC V _{CC} or GND current		±100	mA
T _{stg}	Storage temperature range		-65 to +150	°C
P _{TOT}	Power dissipation per package -plastic medium-shrink (SSOP) -plastic thin-medium-shrink (TSSOP)	For temperature range: -40 to +125 °C above +55°C derate linearly with 11.3 mW/K above +55°C derate linearly with 8 mW/K	850 600	mW

NOTE:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

74ALVCH16825

DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltage are referenced to GND (ground = 0 V).

				LIMITS		
SYMBOL	PARAMETER	TEST CONDITIONS	Temp =	= -40°C to +8	5°C	רואט
			MIN	TYP ¹	MAX	
		V _{CC} = 2.3 to 2.7V	1.7	1.2		
VIH	HIGH level Input voltage	V _{CC} = 2.7 to 3.6V	2.0	1.5		1 ~
		V _{CC} = 2.3 to 2.7V		1.2	0.7	
VIL	LOW level Input voltage	V _{CC} = 2.7 to 3.6V		1.5	0.8	1 ~
		$V_{CC} = 2.3$ to 3.6V; $V_I = V_{IH}$ or V_{IL} ; $I_O = -100\mu A$	V _{CC} -0.2	V _{CC}		
		V_{CC} = 2.3V; V_{I} = V_{IH} or V_{IL} ; I_{O} = -6mA	V _{CC} -0.3	V _{CC} -0.08		1
		$V_{CC} = 2.3V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -12mA$	V _{CC} -0.6	V _{CC} -0.26		1
V _{OH}	HIGH level output voltage	$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -12mA$	V _{CC} -0.5	V _{CC} -0.14		1 ~
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -12mA$	V _{CC} -0.6	V _{CC} -0.09		
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -24mA$	V _{CC} -1.0	V _{CC} -0.28		1
		$V_{CC} = 2.3 \text{ to } 3.6 \text{V}; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu \text{A}$		GND	0.20	V
		$V_{CC} = 2.3V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 6mA$		0.07	0.40	V
V _{OL}	LOW level output voltage	V_{CC} = 2.3V; V_{I} = V_{IH} or V_{IL} ; I_{O} = 12mA		0.15	0.70	
		V_{CC} = 2.7V; V_{I} = V_{IH} or V_{IL} ; I_{O} = 12mA		0.14	0.40	1 v
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 24mA$		0.27	0.55	1
I _I	Input leakage current	$V_{CC} = 2.3 \text{ to } 3.6\text{V};$ $V_{I} = V_{CC} \text{ or GND}$		0.1	5	μA
I _{OZ}	3-State output OFF-state current	V_{CC} = 2.3 to 3.6V; V_I = V_{IH} or V_{IL} ; V_O = V_{CC} or GND		0.1	10	μ/
I _{CC}	Quiescent supply current	V_{CC} = 2.3 to 3.6V; V_{I} = V_{CC} or GND; I_{O} = 0		0.2	40	μ
ΔI_{CC}	Additional quiescent supply current	V_{CC} = 2.3V to 3.6V; V_{I} = V_{CC} – 0.6V; I_{O} = 0		150	750	μA
I _{BHL} ²	Bus hold LOW sustaining current	$V_{CC} = 2.3V; V_{I} = 0.7V$	45	-		μ/
·DUL		$V_{CC} = 3.0V; V_1 = 0.8V$	75	150		μ,
I _{BHH} ²	Bus hold HIGH sustaining current	$V_{CC} = 2.3V; V_{I} = 1.7V$	-45	175		μ/
	Due held I OW eventuring events of	$V_{CC} = 3.0V; V_I = 2.0V$	-75	-175		
I _{BHLO} ² I _{BHHO} ²	Bus hold LOW overdrive current Bus hold HIGH overdrive current	$V_{CC} = 3.6V$ $V_{CC} = 3.6V$	500 500			μA μA

NOTES:

1. All typical values are at $T_{amb} = 25^{\circ}C$. 2. Valid for data inputs of bus hold parts.

74ALVCH16825

AC CHARACTERISTICS FOR V_{CC} = 2.3V TO 2.7V RANGE

 $GND = 0V; \ t_r = t_f \leq 2.0ns; \ C_L = 30pF$

				LIMITS		
SYMBOL	PARAMETER	WAVEFORM	۷c	_C = 2.3 to 2.7	٧٧	UNIT
			MIN	TYP ¹	MAX	
t _{PHL} /t _{PLH}	Propagation delay nAn to nYn	1, 3	1.0	2.0	4.1	ns
t _{PZH} /t _{PZL}	3-State output enable time nOEn to nYn	2, 3	1.0	2.9	6.0	ns
t _{PHZ} /t _{PLZ}	3-State output disable time nOEn to nYn	2,3	1.2	2.2	5.6	ns

NOTE:

1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

AC CHARACTERISTICS FOR V_{CC} = 3.0V TO 3.6V RANGE AND V_{CC} = 2.7V

GND = 0V; $t_r = t_f \le 2.5ns$; $C_L = 50pF$

				LIMITS			LIMITS		
SYMBOL	PARAMETER	WAVEFORM	V _C	$_{ m C}$ = 3.3 \pm 0.	3V		V _{CC} = 2.7V		UNIT
			MIN	TYP ^{1, 2}	MAX	MIN	TYP ¹	MAX	
t _{PHL} /t _{PLH}	Propagation delay nAn to nYn	1, 3	1.0	2.0	3.4	1.0	2.1	3.9	ns
t _{PZH} /t _{PZL}	3-State output enable time nOEn to nYn	2, 3	1.0	2.8	4.7	1.0	2.9	5.7	ns
t _{PHZ} /t _{PLZ}	3-State output disable time nOEn to nYn	2, 3	1.3	2.9	4.5	1.3	3.0	4.9	ns

NOTES:

1. All typical values are measured $T_{amb} = 25^{\circ}C$.

2. Typical value is measured at $V_{CC} = 3.3V$

AC WAVEFORMS FOR V_{CC} = 2.3V TO 2.7V AND V_{CC} < 2.3V RANGE

 $V_{M} = 0.5 V_{CC}$ $V_{X} = V_{OL} + 0.15 V$

 $V_{Y} = V_{OH} - 0.15V$ V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load.

AC WAVEFORMS FOR V_{CC} = 3.0V TO 3.6V AND V_{CC} = 2.7V RANGE

 $V_{M} = 1.5 V$ $V_{X} = V_{OL} + 0.3V$ $V_{\rm Y} = V_{\rm OH} - 0.3 V$ $V_{\mbox{OL}}$ and $V_{\mbox{OH}}$ are the typical output voltage drop that occur with the output load.

 $V_{I} = 2.7V$ $V_{I} = V_{CC}$



Waveform 1. Input (Dn) to output (Yn) propagation delay



Waveform 2. 3-State enable and disable times

74ALVCH16825

TEST CIRCUIT



Waveform 3. Load circuitry for switching times

74ALVCH16825



74ALVCH16825

NOTES

74ALVCH16825

Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

[1] Please consult the most recently issued datasheet before initiating or completing a design.

Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information — Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors make no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Disclaimers

Life support — These products are not designed for use in life support appliances, devices or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips Semiconductors customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips Semiconductors for any damages resulting from such application.

Right to make changes — Philips Semiconductors reserves the right to make changes, without notice, in the products, including circuits, standard cells, and/or software, described or contained herein in order to improve design and/or performance. Philips Semiconductors assumes no responsibility or liability for the use of any of these products, conveys no license or title under any patent, copyright, or mask work right to these products, and makes no representations or warranties that these products are free from patent, copyright, or mask work right infringement, unless otherwise specified.

Philips Semiconductors 811 East Arques Avenue P.O. Box 3409 Sunnyvale, California 94088–3409 Telephone 800-234-7381 © Copyright Philips Electronics North America Corporation 1998 All rights reserved. Printed in U.S.A.

print code

Document order number:

1C

Date of release: 07-98 9397-750-04555

Let's make things better.



PHILIPS